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ADDITIONAL TECHNOLOGIES BY THESE INVENTORS

- A Structure For Increasing Mobility In A High-Electron-Mobility Transistor
- (In,Ga,Al)N Optoelectronic Devices with Thicker Active Layers for Improved Performance
- GaN-based Vertical Metal Oxide Semiconductor and Junction Field Effect Transistors
- Iii-N Transistor With Stepped Cap Layers
- III-N Based Material Structures and Circuit Modules Based on Strain Management

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